

GP2L24J0000F

Detecting Distance : 0.7mm Darlington Phototransistor Output Compact Reflective Photointerrupter



■ Description

GP2L24J0000F is a compact-package, darlington phototransistor output, reflective photointerrupter, with emitter and detector facing the same direction in a molding that provides non-contact sensing. The compact package series is a result of unique technology, combing transfer and injection molding, that also blocks visible light to minimize false detection.

■Features

- 1. Reflective with Darlington Phototransistor Output
- 2. Highlights:
 - Compact Size
- 3. Key Parameters:
 - · Optimal Sensing Distance: 0.7mm
 - Package: 4×3×1.7mm
 - · Visible light cut resin to prevent
- 4. Lead free and RoHS directive compliant

■Agency approvals/Compliance

1. Compliant with RoHS directive

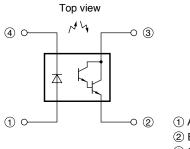
■Applications

- 1. Detection of object presence or motion.
- 2. Example: printer, optical storage

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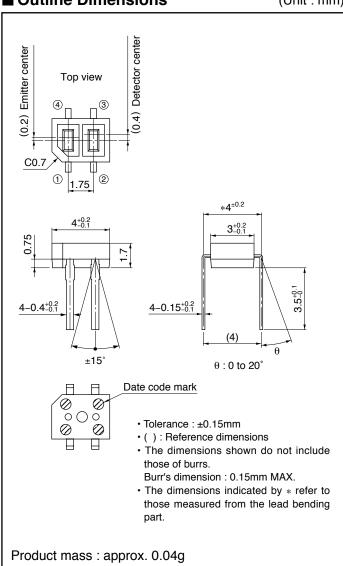
■ Internal Connection Diagram



- 1 Anode
- 2 Emitter
- 3 Collector
- 4 Cathode

■ Outline Dimensions





Plating material: SnCu (Cu: TYP. 2%)



Date code (Symbol)

January



July



February



August



March



September



April



October



Мау



November



June



December



Rank mark

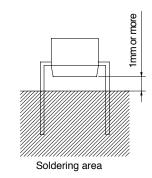
There is no rank indicator.

Country of origin

Japan



■ Abs	■ Absolute Maximum Ratings (T _a =25°C)				
	Parameter	Symbol	Rating	Unit	
Forward current		I_{F}	50	mA	
Input	Reverse voltage	V _R	6	V	
	Power dissipation	P_{D}	75	mW	
	Collector-emitter voltage	V _{CEO}	35	V	
Outmut	Emitter-collector voltage	V _{ECO}	6	V	
Output	Collector current	$I_{\rm C}$	50	mA	
	Collector power dissipation	P _C	75	mW	
Total power dissipation		P _{tot}	100	mW	
Operating temperature		T _{opr}	-25 to +85	°C	
Storage temperature		T _{stg}	-40 to +100	°C	
*1Soldering temperature		T _{sol}	260	°C	



■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

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	Parameter		Symbol	Condition	MIN.	TYP.	MAX.	Unit
Innut	Forward voltage		$V_{\rm F}$	I _F =20mA	_	1.2	1.4	V
Input	Reverse current		I_R	V _R =6V	_	_	10	μΑ
Output	Collector dark curr	ent	I_{CEO}	V _{CE} =10V	_	_	1	nA
Tuonofon	*2 Collector current		I_{C}	$I_F=4mA$, $V_{CE}=2V$	0.5	3	15	mA
Transfer charac-	*3 Leak current		I _{LEAK}	$I_F=4mA, V_{CE}=5V$	_	_	5	nA
teristics	Response time	Rise time	t _r	$V_{CE}=2V, I_{C}=10\mu A,$	_	80	400	
		Fall time	$t_{\rm f}$	$R_L=100\Omega$, $d=1mm$	_	70	400	μs

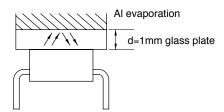
^{*2} The condition and arrangement of the reflective object are shown below.

The rank splitting of collector current (I_C) shall be executed according to the table below.

Rank	$\begin{array}{c} \text{Collector current, I}_{C} [\text{mA}] \\ (I_{F}\!\!=\!\!4\text{mA}, V_{CE}\!\!=\!\!2V) \end{array}$	Package sleeve color
A	0.5 to 1.9	Yellow
В	1.45 to 5.4	Transparent
С	4 to 15	Green

^{*3} Without reflective object.

● Test Arrangement for Collector Current



^{*1} For 5s or less.



■ Model Line-up

·				
Model No.	Rank	Collector current I _C [mA]		
Wiodel No.		$(I_F=4mA, V_{CE}=2V, T_a=25^{\circ}C)$		
GP2L24J0000F	A, B or C	0.5 to 15		
GP2L24BJ000F	В	1.45 to 5.4		
GP2L24CJ000F	С	4 to 15		
GP2L24ABJ00F	A or B	0.5 to 5.4		
GP2L24BCJ00F	B or C	1.45 to 15		

^{*} The ratio of each rank can not be guaranteed.

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs.

Ambient Temperature

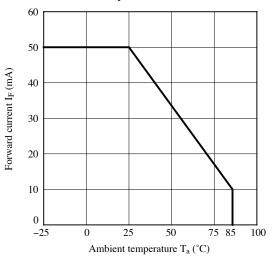


Fig.3 Peak Forward Current vs. Duty Ratio

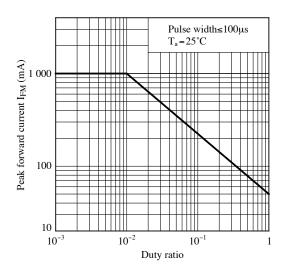


Fig.5 Collector Current vs. Forward Current

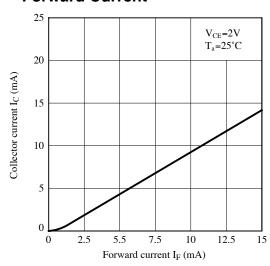


Fig.2 Collector Power Dissipation vs. Ambient Temperature

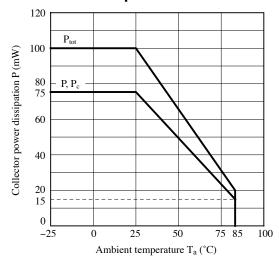


Fig.4 Forward Current vs. Forward Voltage

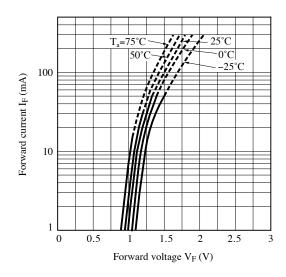


Fig.6 Collector Current vs.
Collector-emitter Voltage

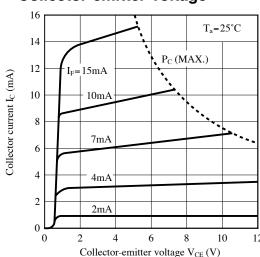




Fig.7 Relative Collector Current vs.
Ambient Temperature

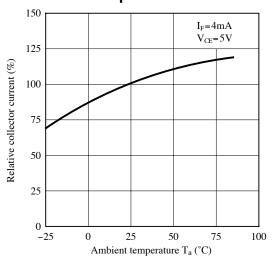


Fig.9 Response Time vs. Load Resistance

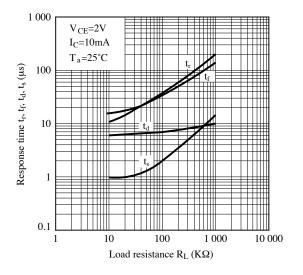


Fig.11 Relative Collector Current vs. Distance (Reference value)

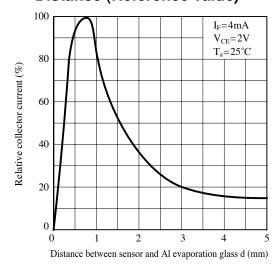


Fig.8 Collector Dark Current vs.
Ambient Temperature

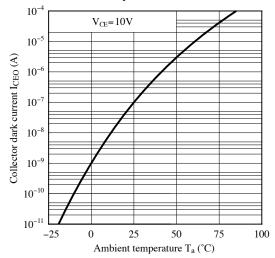


Fig.10 Test Circuit for Response Time

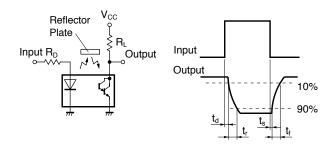


Fig.12 Detecting Position Characteristics (1)

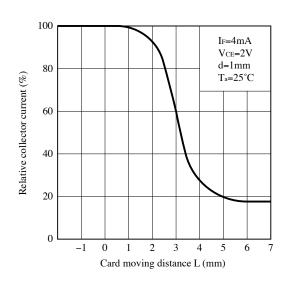




Fig.13 Detecting Position Characteristics (2)

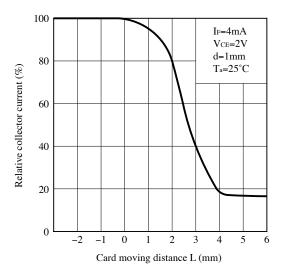


Fig.14 Test Condition for Distance & Detecting Position Characteristics

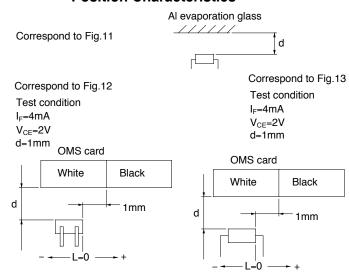


Fig.15 Frequency Response

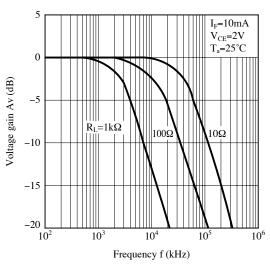
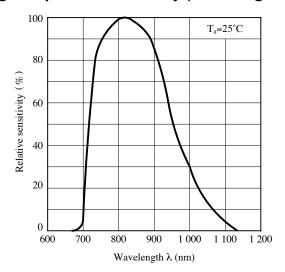


Fig.16 Spectral Sensitivity (Detecting side)



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

1) Prevention of detection error

To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.

2) Distance characteristic

Please refer to Fig.11 (Relative collector current vs. Distance) to set the distance of the photointerrupter and the object.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photointerrupter will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Parts

This product is assembled using the below parts.

• Photodetector (qty.: 1)

Category	Material	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Phototransister	Silicon (Si)	800	700 to 1 200	80

Photo emitter (qty.: 1)

Category	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3

Material

Case	Lead frame	Lead frame plating
Black polyphenylene	42Alloy	SnCu plating



■ Manufacturing Guidelines

Soldering Method

Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Soldering area is 1mm or more away from the bottom of housing.

Please take care not to let any external force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning:

Do not execute ultrasonic cleaning.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

● Sleeve package

Package materials

Sleeve: Polystyrene

Stopper: Styrene-Butadiene

Package method

MAX. 50 pcs. of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

MAX. 40 sleeves in one case.

Color of sleeve

Rank classification is distinguished by the color of the sleeve as shown in the table below. But the ratio of each rank can not be guaranteed.

Rank	Color of sleeve
A	Yellow
В	Transparent
С	Green



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- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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